

RoHS

COMPLIANT HALOGEN FREE Available

Vishay Siliconix

N-Channel Q_g, Fast Switching MOSFET

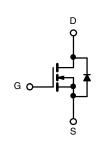
PRODUCT SUMMARY					
V _{DS} (V)	R_{DS(on)} (Ω)	I _D (A)			
30	0.0095 at V _{GS} = 10 V	12.5			
	0.0135 at V _{GS} = 4.5 V	10.5			

FEATURES

- Halogen-free According to IEC 61249-2-21 Definition
- Extremely Low Q_{gd} for Switching Losses
 TrenchFET[®] Power MOSFET
- 100 % R_g Tested •
- Compliant to RoHS Directive 2002/95/EC

APPLICATIONS

- High-Side DC/DC Conversion
 - Notebook
 - Server



8 D D 2 7 D 6 D 5 Top View

Ordering Information: Si4390DY-T1-E3 (Lead (Pb)-free) Si4390DY-T1-GE3 (Lead (Pb)-free and Halogen-free)

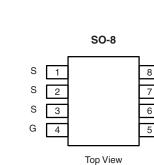
N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS ($T_A = 25 \degree C$, unless otherwise noted)						
Parameter		Symbol	10 s	Steady State	Unit	
Drain-Source Voltage		V _{DS}	30		V	
Gate-Source Voltage		V _{GS}	± 20			
Continuous Drain Current $(T_J = 150 \ ^{\circ}C)^a$	T _A = 25 °C	– I _D	12.5	8.5		
	T _A = 70 °C		10	6.8	А	
Pulsed Drain Current		I _{DM}	20		A	
Continuous Source Current (Diode Conduction) ^a		ا _S	2.7	1.3		
Maximum Power Dissipation ^a	T _A = 25 °C	PD	3.0	1.4	W	
	T _A = 70 °C	гD	1.9	0.9	vv	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55	to 150	°C	

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Maximum Junction-to-Ambient ^a	t ≤ 10 s	R _{thJA}	32	42	
	Steady State		68	90	°C/W
Maximum Junction-to-Foot (Drain)	Steady State	R _{thJF}	15	20	

Notes:

a. Surface mounted on 1" x 1" FR4 board.



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Parameter	Symbol	Test Conditions		Тур.	Max.	Unit	
Static							
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \ \mu A$	0.8		2.8	V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA	
		$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}$			1		
Zero Gate Voltage Drain Current	DSS	V_{DS} = 30 V, V_{GS} = 0 V, T_{J} = 55 °C			5	μΑ	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5$ V, V_{GS} = 10 V	30			А	
Drain-Source On-State Resistance ^a	Р	V _{GS} = 10 V, I _D = 12.5 A		0.0075	0.0095		
	R _{DS(on)}	$V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 10.5 \text{ A}$		0.0105	0.0135	Ω	
Forward Transconductance ^a	g _{fs}	V _{DS} = 15 V, I _D = 12.5 A		38		S	
Diode Forward Voltage ^a	V _{SD}	$I_{S} = 2.7 \text{ A}, V_{GS} = 0 \text{ V}$		0.7	1.1	V	
Dynamic ^b	· · · · · ·			•			
Total Gate Charge	Qg			10	15		
Gate-Source Charge	Q _{gs}	V_{DS} = 15 V, V_{GS} = 4.5 V, I_{D} = 12.5 A		3.5		nC	
Gate-Drain Charge	Q _{gd}			2.1			
Gate Resistance	R _g		0.2	0.8	1.4	Ω	
Turn-On Delay Time	t _{d(on)}			16	30		
Rise Time	t _r	V_{DD} = 15 V, R_L = 15 Ω		6	12]	
Turn-Off Delay Time	t _{d(off)}	${\rm I}_{\rm D} \cong$ 1 A, ${\rm V}_{\rm GEN}$ = 10 V, ${\rm R}_{\rm g}$ = 6 Ω		43	70	ns	
Fall Time	t _f			14	25	1	
Source-Drain Reverse Recovery Time	t _{rr}	I _F = 2.7 A, dl/dt = 100 A/μs		35	60		

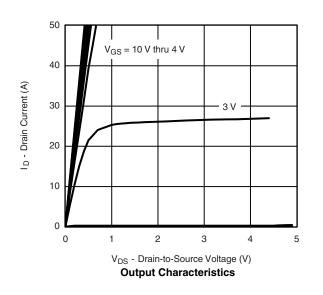
Notes:

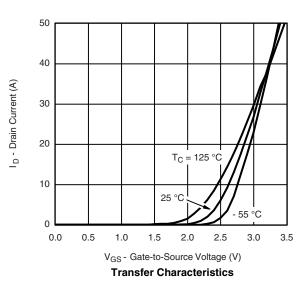
a. Pulse test; pulse width \leq 300 $\mu s,$ duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)





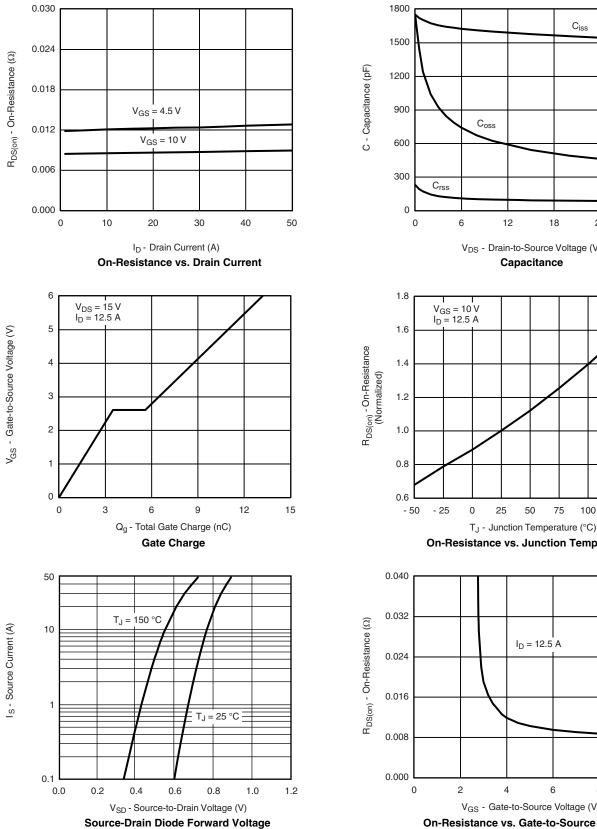


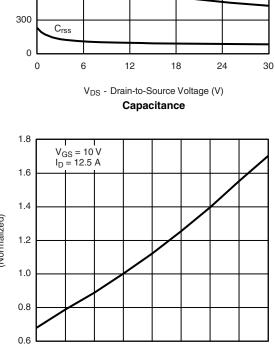
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TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)





On-Resistance vs. Junction Temperature

50

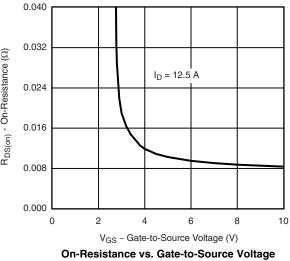
75

100

125

150

25



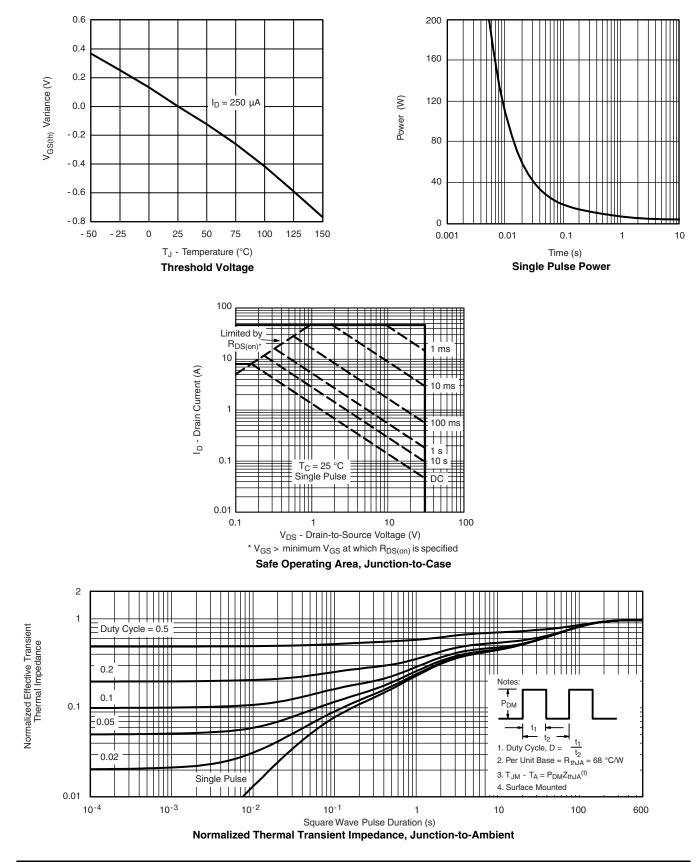
Document Number: 72150 S11-0209-Rev. F, 14-Feb-11

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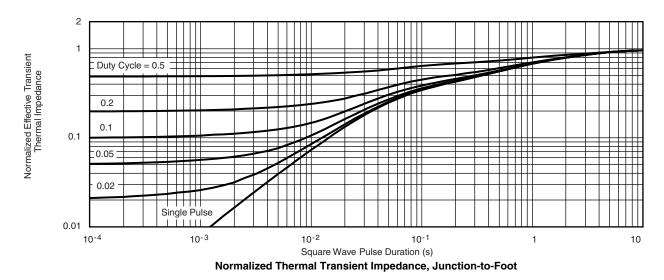




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TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?72150.



Package Information

Vishay Siliconix

SOIC (NARROW): 8-LEAD JEDEC Part Number: MS-012





	MILLIM	IETERS	INCHES			
DIM	Min	Мах	Min	Max		
A	1.35	1.75	0.053	0.069		
A ₁	0.10	0.20	0.004	0.008		
В	0.35	0.51	0.014	0.020		
С	0.19	0.25	0.0075	0.010		
D	4.80	5.00	0.189	0.196		
E	3.80	4.00	0.150	0.157		
е	1.27	BSC	0.050 BSC			
н	5.80	6.20	0.228	0.244		
h	0.25	0.50	0.010	0.020		
L	0.50	0.93	0.020	0.037		
q	0°	8°	0°	8°		
S	0.44	0.64	0.018	0.026		
ECN: C-06527-Rev. I, 11-Sep-06 DWG: 5498						

Application Note 826

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RECOMMENDED MINIMUM PADS FOR SO-8



Recommended Minimum Pads Dimensions in Inches/(mm)

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